

SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 20 --- 40 V
CURRENT: 1.0 A

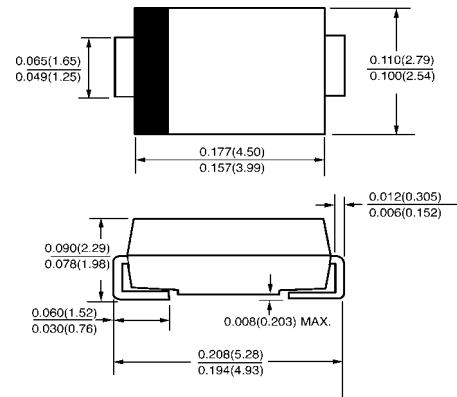
FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-214AC, molded plastic
- ◇ Terminals: Solderable per MIL-STD-202, method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.002 ounces, 0.064 gram
- ◇ Mounting position: Any

SMA(DO-214AC)



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		S5817	S5818	S5819	UNITS
Device marking code		S17	S18	S19	
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	V
Maximum RMS voltage	V_{RMS}	14	21	28	V
Maximum DC blocking voltage	V_{DC}	20	30	40	V
Maximum average forward rectified current @ $T_L = 90^\circ C$	$I_{F(AV)}$	1.0			A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	25			A
Maximum instantaneous forward voltage @ 1.0A (Note 1) @ 3.0A	V_F	0.45 0.75	0.55 0.875	0.60 0.90	V
Maximum reverse current @ $T_A = 25^\circ C$ at rated DC blocking voltage @ $T_A = 100^\circ C$	I_R	1.0 10			mA
Typical junction capacitance (Note2)	C_J	110			pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50			$^\circ C/W$
Operating junction temperature range	T_J	- 55 ---- + 125			$^\circ C$
Storage temperature range	T_{STG}	- 55 ---- + 150			$^\circ C$

NOTE: 1. Pulse test : 300 μs pulse width, 1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

www.galaxycn.com

FIG.1 – FORWARD DERATING CURVE

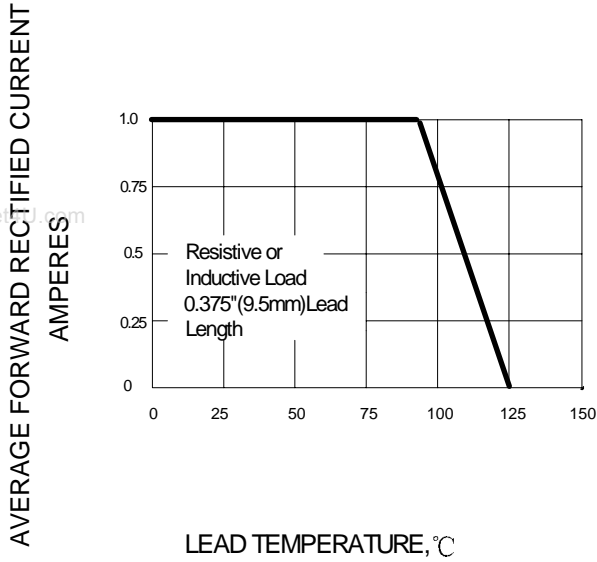


FIG.2 – PEAK FORWARD SURGE CURRENT

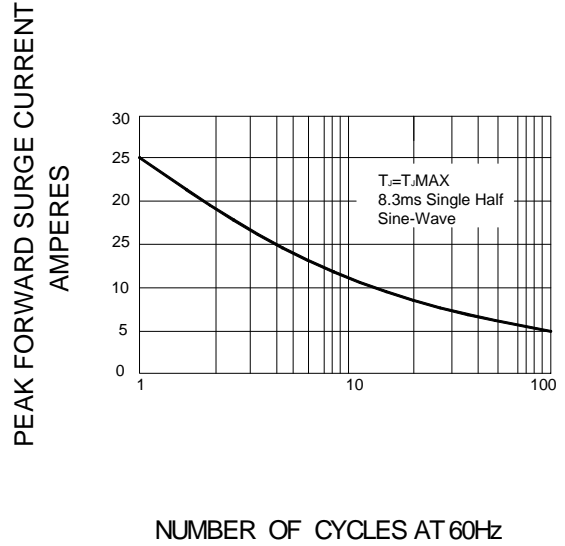


FIG.3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

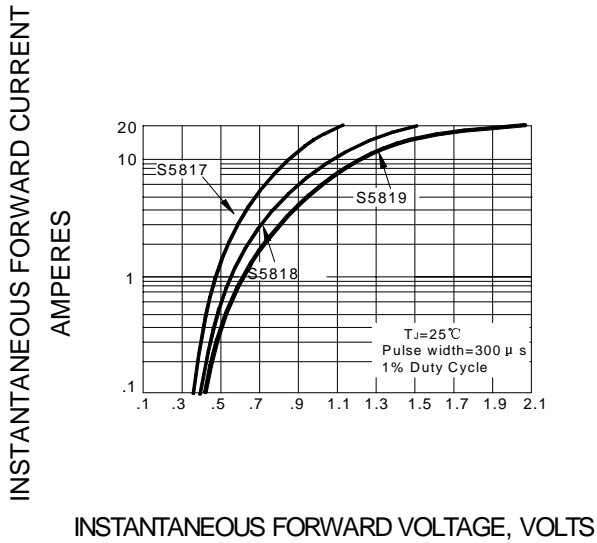


FIG.4 – TYPICAL JUNCTION CAPACITANCE

